

Data sheet acquired from Harris Semiconductor SCHS132C

August 1997 - Revised September 2003

Features

- Buffered Inputs
- Typical Propagation Delay: 7ns at V_{CC} = 5V, C_L = 15pF, T_A = 25°C
- Fanout (Over Temperature Range)
 - Standard Outputs..... 10 LSTTL Loads
 - Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, II \leq 1µA at VOL, VOH

CD54HC27, CD74HC27, CD54HCT27, CD74HCT27

High-Speed CMOS Logic Triple 3-Input NOR Gate

Description

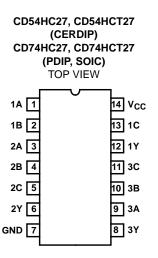
The 'HC27 and 'HCT27 logic gates utilize silicon gate CMOS technology to achieve operating speeds similar to LSTTL gates with the low power consumption of standard CMOS integrated circuits. All devices have the ability to drive 10 LSTTL loads. The HCT logic family is functionally pin compatible with the standard LS logic family.

Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC27F3A	-55 to 125	14 Ld CERDIP
CD54HCT27F3A	-55 to 125	14 Ld CERDIP
CD74HC27E	-55 to 125	14 Ld PDIP
CD74HC27M	-55 to 125	14 Ld SOIC
CD74HC27MT	-55 to 125	14 Ld SOIC
CD74HC27M96	-55 to 125	14 Ld SOIC
CD74HCT27E	-55 to 125	14 Ld PDIP
CD74HCT27M	-55 to 125	14 Ld SOIC
CD74HCT27MT	-55 to 125	14 Ld SOIC
CD74HCT27M96	-55 to 125	14 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

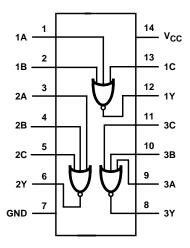
Pinout



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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Functional Diagram

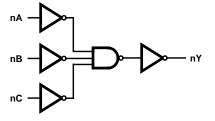


TRUTH TABLE

	INPUTS								
nA	nB	nY							
L	L	L	Н						
L	L	Н	L						
L	Н	L	L						
Н	L	L	L						
Н	Н	L	L						
L	Н	Н	L						
Н	L	Н	L						
Н	Н	Н	L						

H = High Voltage Level, L = Low Voltage Level

Logic Symbol



Absolute Maximum Ratings

DC Supply Voltage, V _{CC}
DC Input Diode Current, I _{IK}
For $V_{I} < -0.5V$ or $V_{I} > V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, IOK
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC or} I _{GND} ±50mA
Operating Conditions

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Temperature Range (T _A)
Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (^o C/W)
E (PDIP) Package	80
M (SOIC) Package	86
Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TE COND	ST ITIONS		25 ⁰ C		-40 ⁰ C 1	O 85°C	-55°С Т	O 125 ⁰ C							
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX						
HC TYPES																	
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V					
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V					
				6	4.2	-	-	4.2	-	4.2	-	V					
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V					
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V					
				6	-	-	1.8	-	1.8	-	1.8	V					
High Level Output	V _{OH}	V _{IH} or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V					
Voltage CMOS Loads		VIL	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V					
								-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output					-	-	-	-	-	-	-	-	-	V			
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V					
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V					
Low Level Output	V _{OL}	V _{IH} or	0.02	2	-	-	0.1	-	0.1	-	0.1	V					
Voltage CMOS Loads		VIL	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V					
			0.02	6	-	-	0.1	-	0.1	-	0.1	V					
Low Level Output			-	-	-	-	-	-	-	-	-	V					
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V					
			5.2	6	-	-	0.26	-	0.33	-	0.4	V					
Input Leakage Current	ų	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA					

CD54HC27, CD74HC27, CD54HCT27, CD74HCT27

			ST ITIONS			25 ⁰ C		-40°C TO 85°C		-55°С Т	O 125 ⁰ C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	2	-	20	-	40	μA
HCT TYPES	•								•			•
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	VIL	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	2	-	20	-	40	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

DC Electrical Specifications (Continued

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS
All	1.5

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Specifications table, e.g. $360\mu A$ max at $25^{\circ}C$.

Switching Specifications Input t_r , $t_f = 6ns$

		TEST	v _{cc}		25 ⁰ C		-40 ^o C T	O 85°C	-55°C T	O 125ºC	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES		-									
Propagation Delay, Input to	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	95	-	120	-	145	ns
Output (Figure 1)			4.5	-	-	19	-	24	-	29	ns
			6	-	-	16	-	20	-	25	ns
Propagation Delay, Data Input to Output Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	7	-	-	-	-	-	ns

CD54HC27, CD74HC27, CD54HCT27, CD74HCT27

		TEST CONDITIONS	v _{cc}	Vac			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL		(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
Transition Times (Figure 1)	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	26	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay, Input to Output (Figure 2)	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	23	-	29	-	35	ns
Propagation Delay, Data Input to Output Y	t _{PLH} , t _{PHL}	C _L = 15pF	5	-	9	-	-	-	-	-	ns
Transition Times (Figure 2)	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	28	-	-	-	-	-	pF

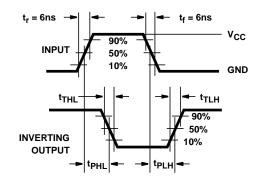
Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

NOTES:

3. C_{PD} is used to determine the dynamic power consumption, per gate.

4. $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms





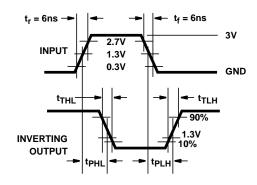


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
5962-8970301CA	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD54HC27F3A	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD54HCT27F3A	ACTIVE	CDIP	J	14	1	None	Call TI	Level-NC-NC-NC
CD74HC27E	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HC27M	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC27M96	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HC27MT	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT27E	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74HCT27M	ACTIVE	SOIC	D	14	50	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT27M96	ACTIVE	SOIC	D	14	2500	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM
CD74HCT27MT	ACTIVE	SOIC	D	14	250	Pb-Free (RoHS)	CU NIPDAU	Level-2-260C-1 YEAR/ Level-1-235C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-012 variation AB.



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